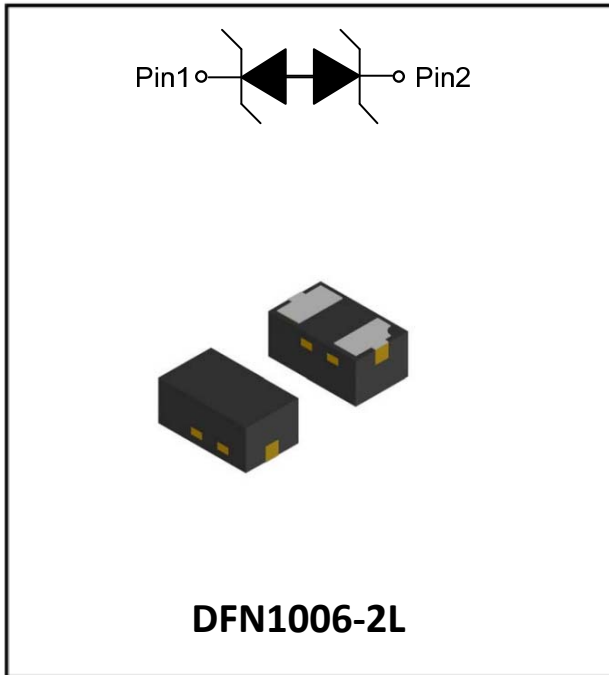


1- Line, Bi-directional, Ultra-low Capacitance, ESD protection diode



Features

- Transient protection for each line according to IEC61000-4-2(ESD): $\pm 16\text{kV}$ contact, $\pm 16\text{kV}$ air IEC61000-4-5:4A($t_p=8/20\mu\text{s}$)
- Ultra Low leakage current
- Ultra low clamping voltage
- Ultra low capacitance
- RoHS Compliant
- Part no. with suffix "Q" means AEC-Q101 qualified

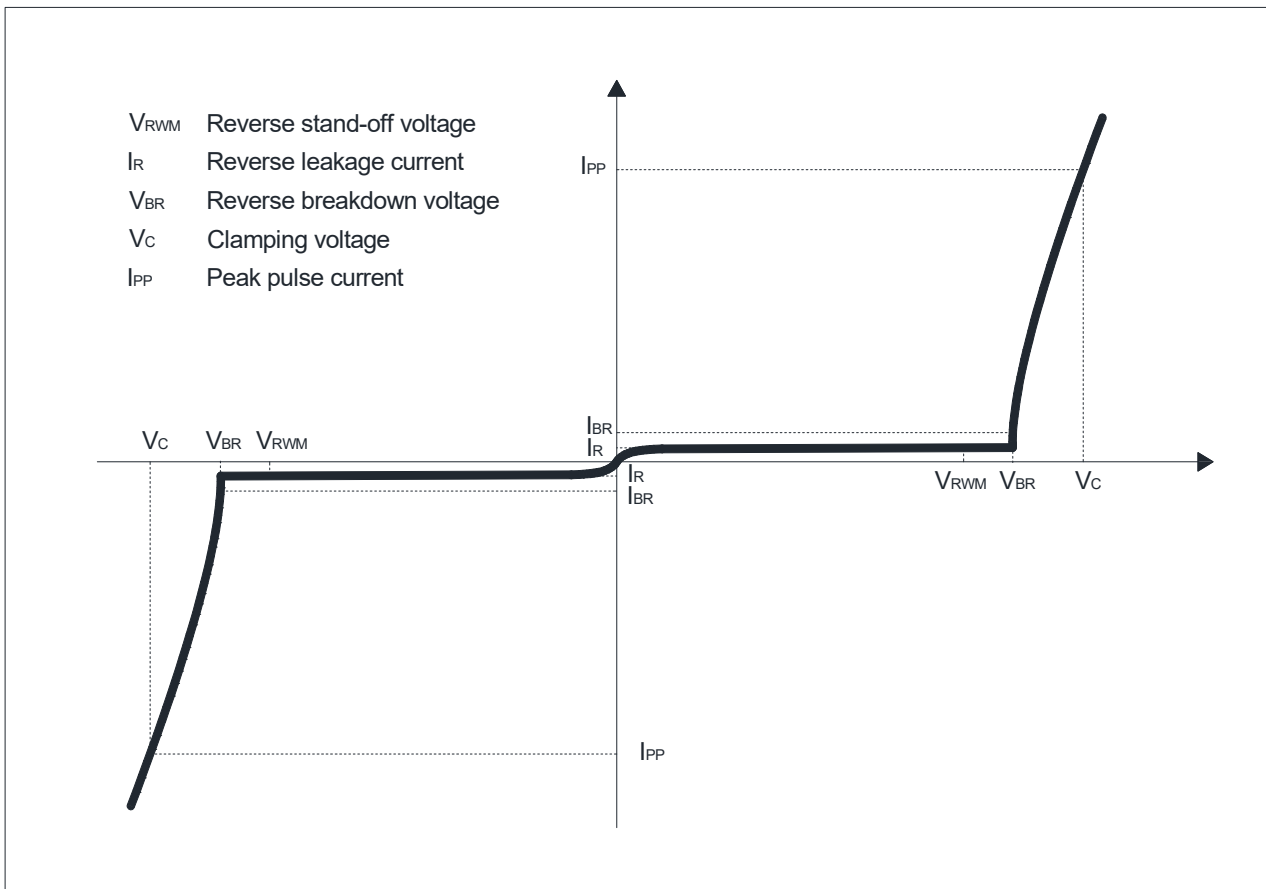
Applications

- Automotive applications

Mechanical Data

- Package: DFN1006-2L
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound
- Moisture Sensitivity: Level 1 per J-STD-020

■ Definitions of electrical characteristics





ESDSL3V3LBQ

■Maximum Ratings

PARAMETER	SYMBOL	LIMITS	UNIT
Peak pulse power ($t_p = 8/20\mu s$)	P_{pk}	80	W
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 16	KV
ESD according to IEC61000-4-2 contact discharge		± 16	
Junction temperature	T_J	-55~150	$^{\circ}C$
Storage temperature	T_{STG}	-55~150	$^{\circ}C$

Notes:

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

■Electrical Characteristics ($T_J=25^{\circ}C$)

PARAMETER	Symbol	UNIT	Conditions	Min	Typ	Max
Reverse Standoff Voltage	V_{RWM}	V				3.3
Reverse breakdown voltage	V_{BR}	V	$I_{BR} = 1mA$	4.8		7.0
Reverse leakage current	I_R	nA	$V_{RWM} = 3.3V$			100
Clamping voltage ¹⁾	V_C	V	$I_{PP} = 1A, t_p = 8/20\mu s$			12
			$I_{PP} = 4A, t_p = 8/20\mu s$			20
Peak Pulse Current	I_{PP}	A	$t_p = 8/20\mu s$			4
Junction capacitance	C_J	pF	$V_R = 0V, f = 1MHz$		0.32	0.65

Notes:

(1). Non-repetitive current pulse, according to IEC61000-4-5.

■Ordering Information (Example)

PREFERED P/N	PACKING CODE	UNIT WEIGHT(mg)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
ESDSL3V3LBQ	F1	Approximate 0.9	10K	100K	400K	Tape&Reel



■ Characteristics (Typical)

Fig.1: 8/20 μ s Pulse Waveform

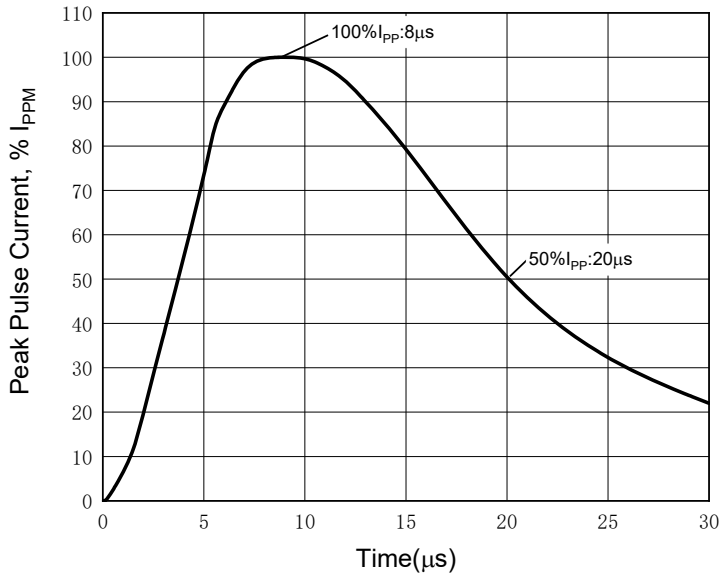


Fig.2: Peak Pulse Current vs Clamping Voltage

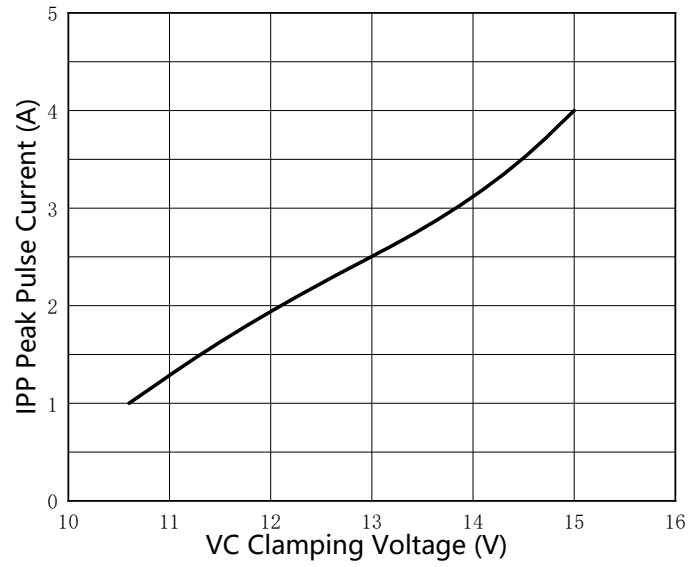


Fig.3: Power Derating Curve

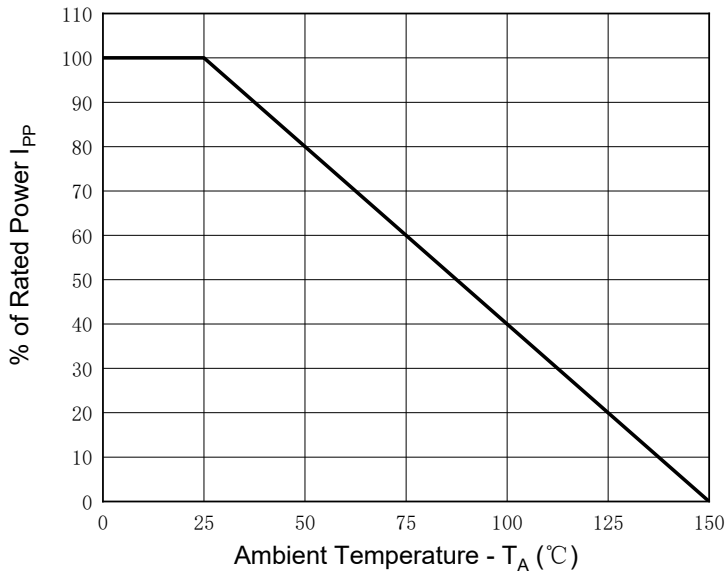
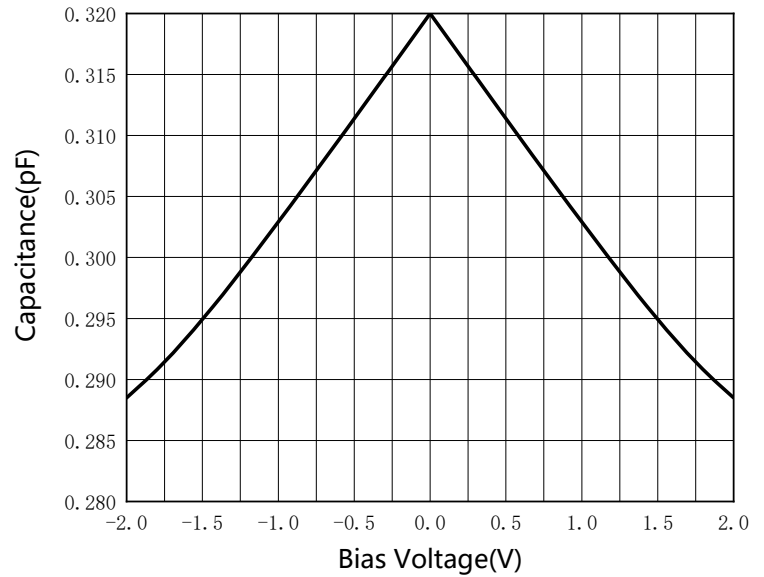


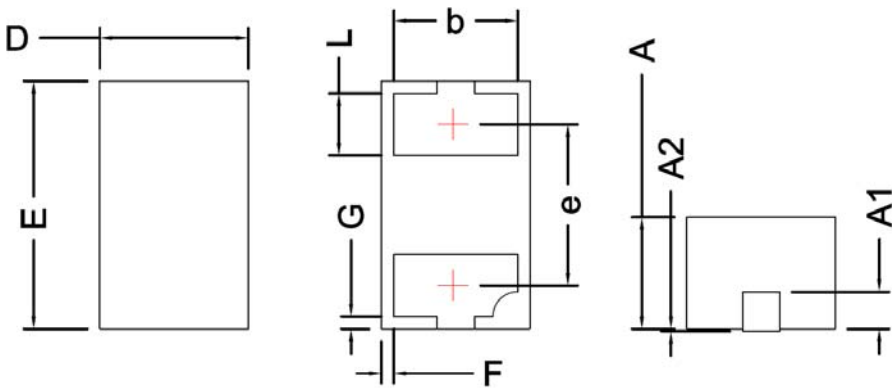
Fig.4: Capacitance vs. Bias



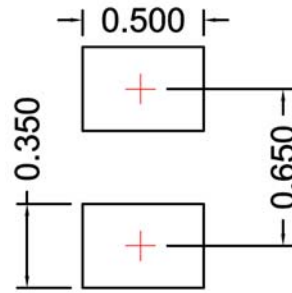


ESDSL3V3LBQ

■ Outline Dimensions



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
D	0.50	0.60	0.70
E	0.90	1.00	1.10
A	0.35	0.45	0.55
A1	0.15 BSC		
A2			0.10
F	0.005		
G	0.005		
L	0.15	0.25	0.35
b	0.41	0.50	0.59
e	0.65 BSC		



Unit: mm

■ Marking Information



Note:

1. All marking is at middle of the product body
2. All marking is in laser marking
3. Body color: Black



ESDSL3V3LBQ

Disclaimer

The information presented in this document is for reference only. Yangzhou Yangjie Electronic Technology Co., Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise.

The product listed herein is designed to be used with automotive electronics, are not designed for use in medical, life-saving, lifesustaining, or military, Yangjie or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website [http:// www.21yangjie.com](http://www.21yangjie.com) , or consult your nearest Yangjie's sales office for further assistance.